

Thermal and Nonthermal Physiochemical Processes in Nanoscale Films of Amorphous Solid Water

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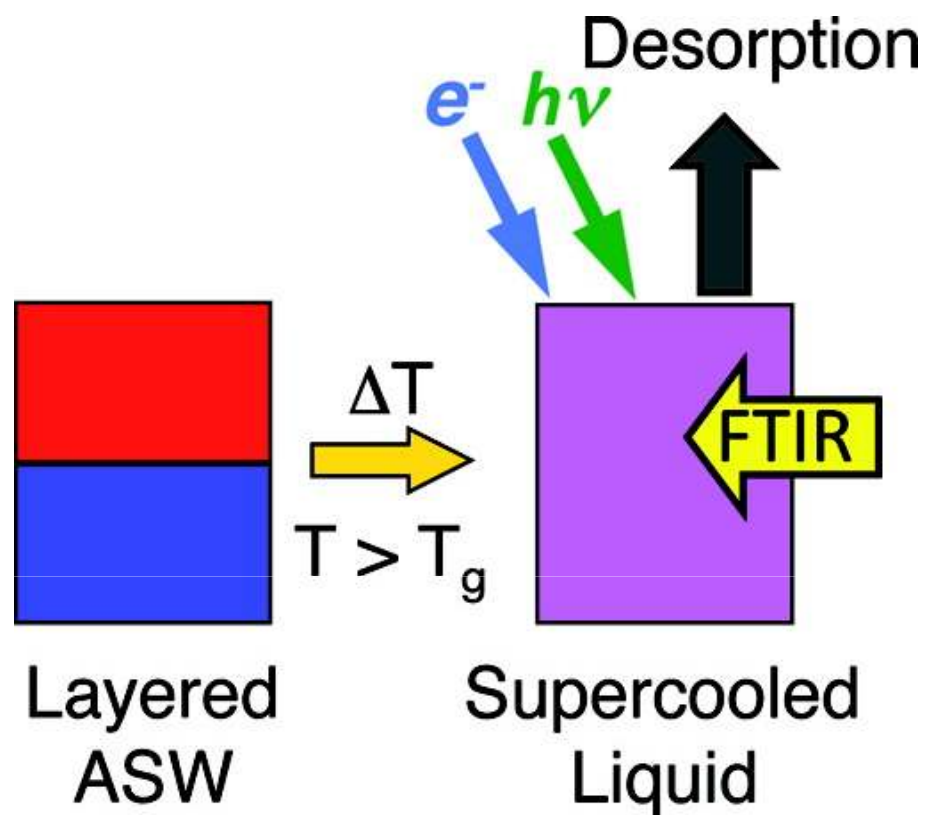
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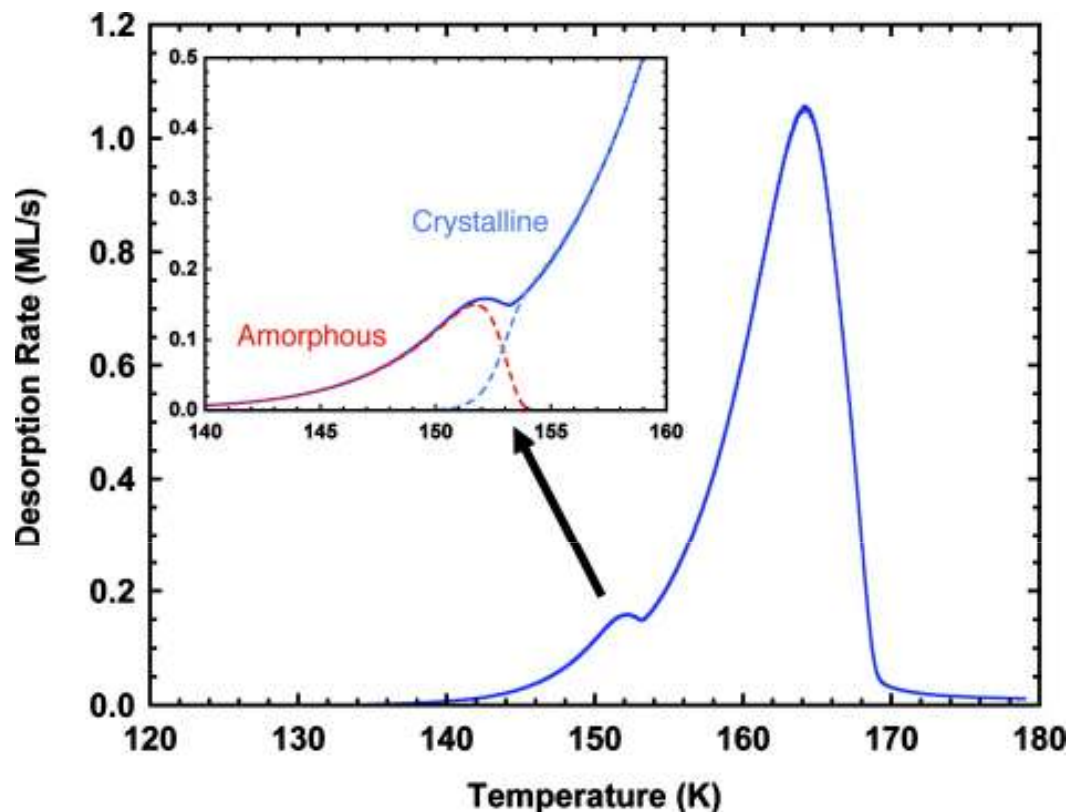
Introduction:

- Amorphous solid water (ASW) is a disordered form of ice created by vapor deposition onto a cold substrate (< 130 K).
 - ASW is a convenient model system for studying the stability of amorphous and glassy materials as well as the properties of highly porous materials.
 - By using molecular beam technique it is possible to control the deposition conditions to create compositionally tailored, nanoscale films of ASW at low temperature.
 - The use of nanoscale films allows to probe the physical and chemical properties of ASW films at temperatures near where they transform into deeply supercooled liquids prior to crystallization.
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- ❖ In this account properties of ASW (thermal properties of ASW and non thermal reactions in ASW films) have been presented by using molecular beams and surface science technique.
 - ❖ Experiments were conducted in UHV chamber.

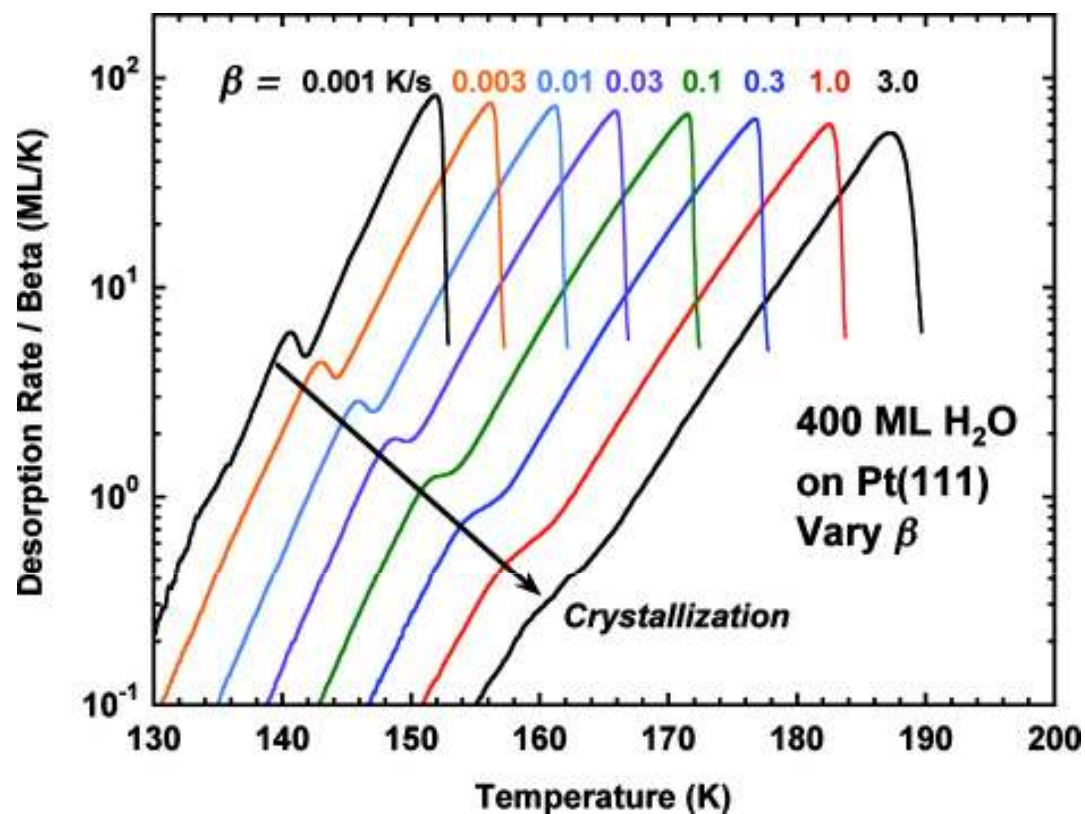


Thermal Properties of ASW:

A. Desorption and crystallization.

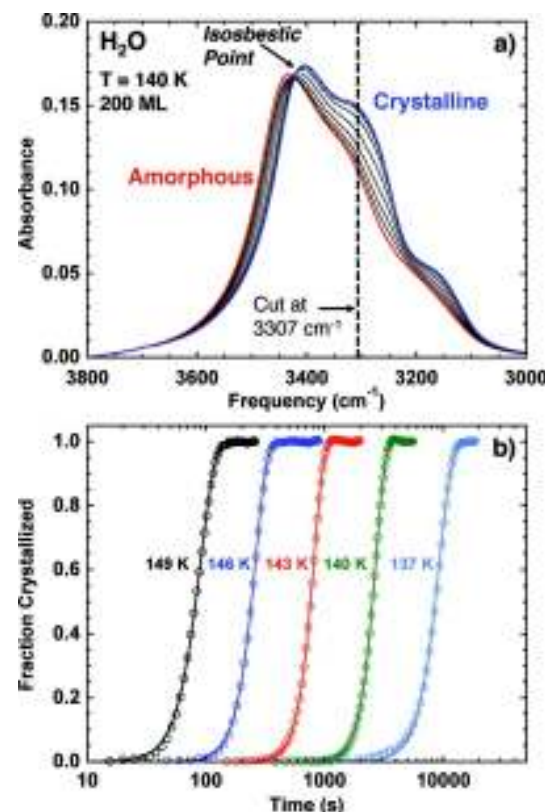


TPD spectrum from a 100 ML ASW film of H₂O deposited at normal incidence at 20 K on a Pt(111) substrate. The film was heated at 0.1 K/s.



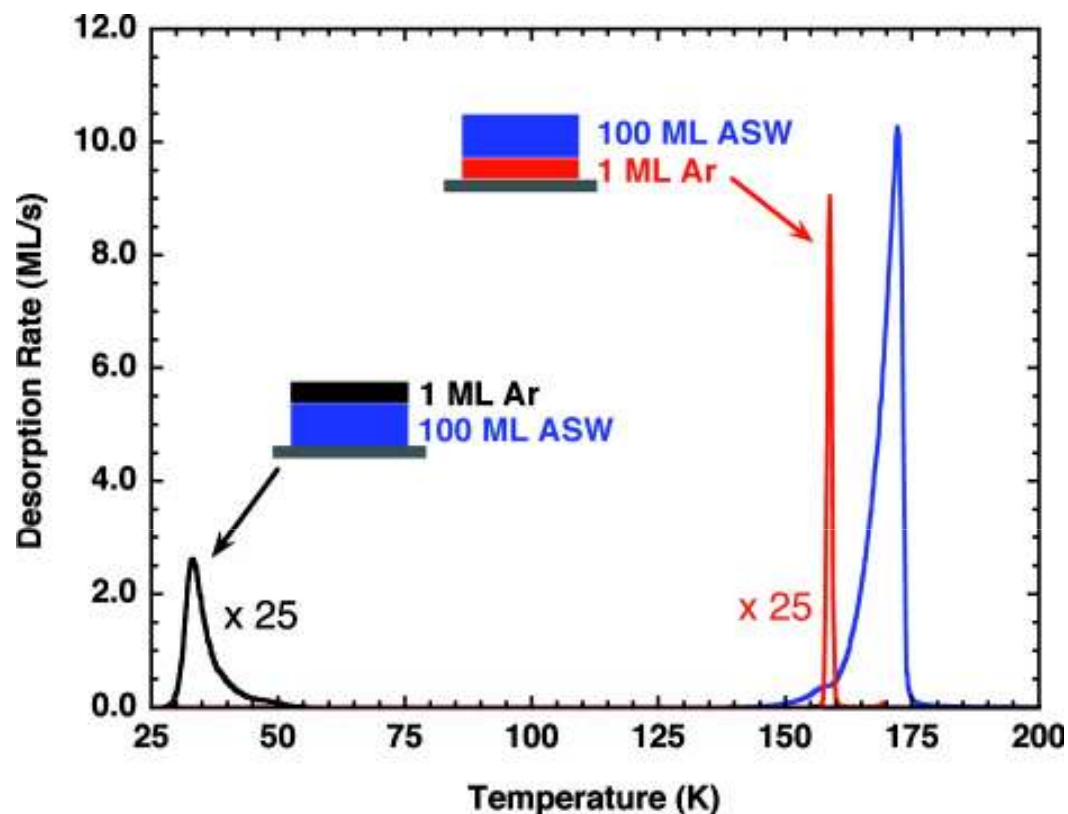
TPD spectra from 400 ML ASW films deposited at normal incidence and 20 K and then heated at various ramp rates. The spectra are plotted as the desorption rate (ML/s) divided by the ramp rate (K/s).

Avrami equation, $x(t) = 1 - \exp(-kt^n)$, where t is time, k is the phenomenological rate constant, and n is related to the crystallization mechanism. For all temperatures, the fit values of n were near 4.



(a) Time-resolved infrared spectra of the OH stretch region of a 200 ML film. The first spectrum (red) is from a completely amorphous film, and the last spectrum (blue) is from a crystallized film. (b) The fraction crystallized versus time for a series of 200 ML films (symbols) held at several isothermal temperatures.

Crystallization of ASW can result in structural changes in the film...



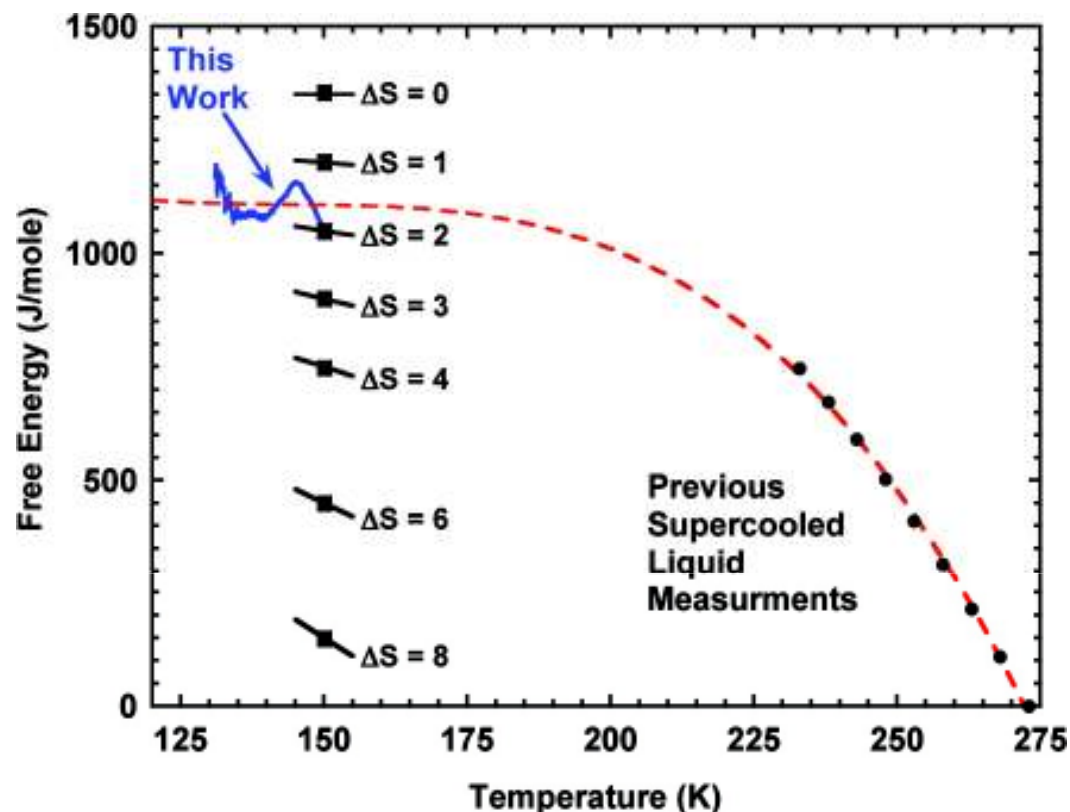
TPD spectra for 1 ML of Ar deposited on top (black) and underneath (red) of 100 ML ASW (blue) films.

❖ The extent to which ices can trap and retain gases can be important in determining the chemical composition of astrophysical bodies.

B. Free energy.

The free-energy difference between the amorphous and crystalline phases is given by $\Delta G = RT \ln(\text{rate}_{\text{amorphous}}/\text{rate}_{\text{crystalline}})$.

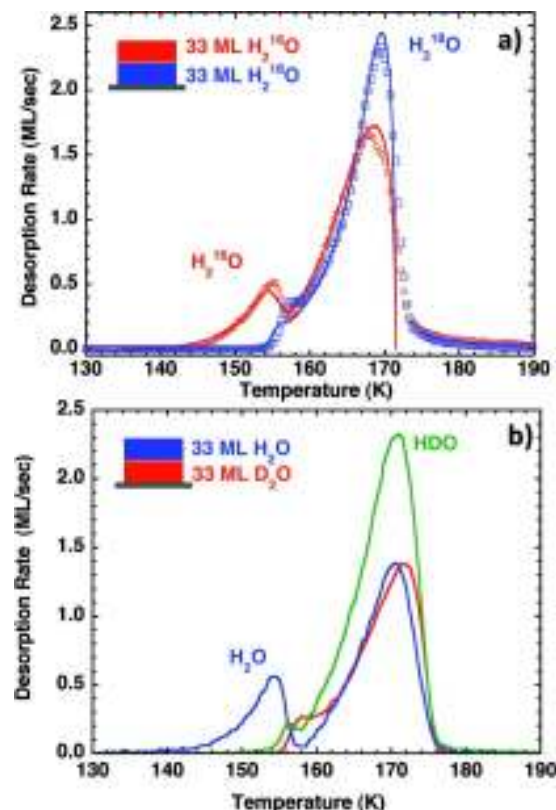
Estimated free energy = 1100 ± 50 kJ/mol and the entropy = 1.6 ± 1 J/(mol K) at temperatures near 150 K.



The experimental excess free energy for ASW (blue line) calculated from the ASW and crystalline desorption rates and for supercooled liquid H₂O (circles) from the literature.

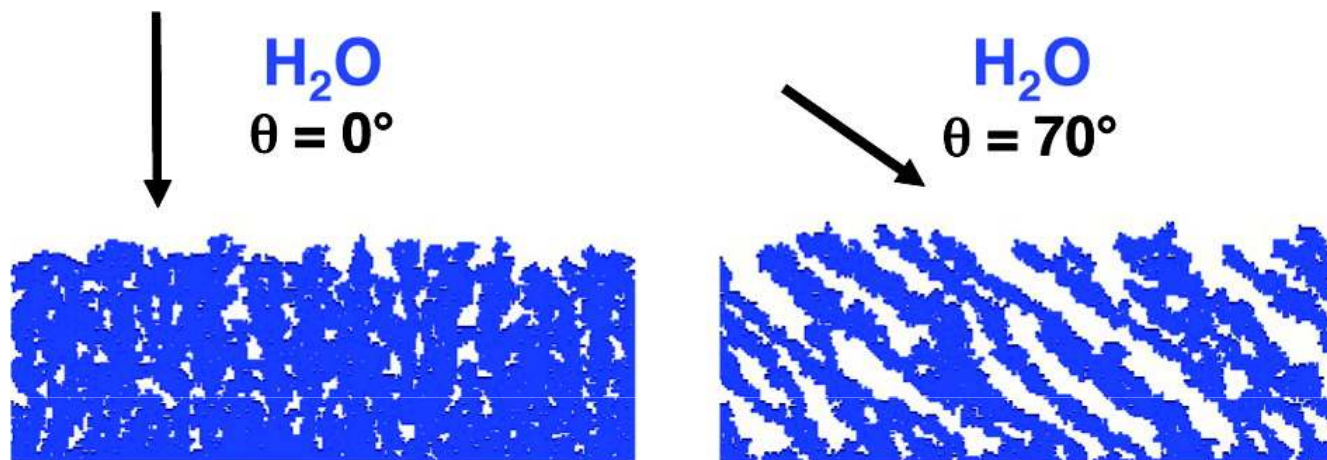
C. Diffusivity.

The extracted diffusivities range from $\sim 1 \times 10^{-15}$ cm²/s at 150 K to $\sim 1 \times 10^{-12}$ cm²/s near 160 K.

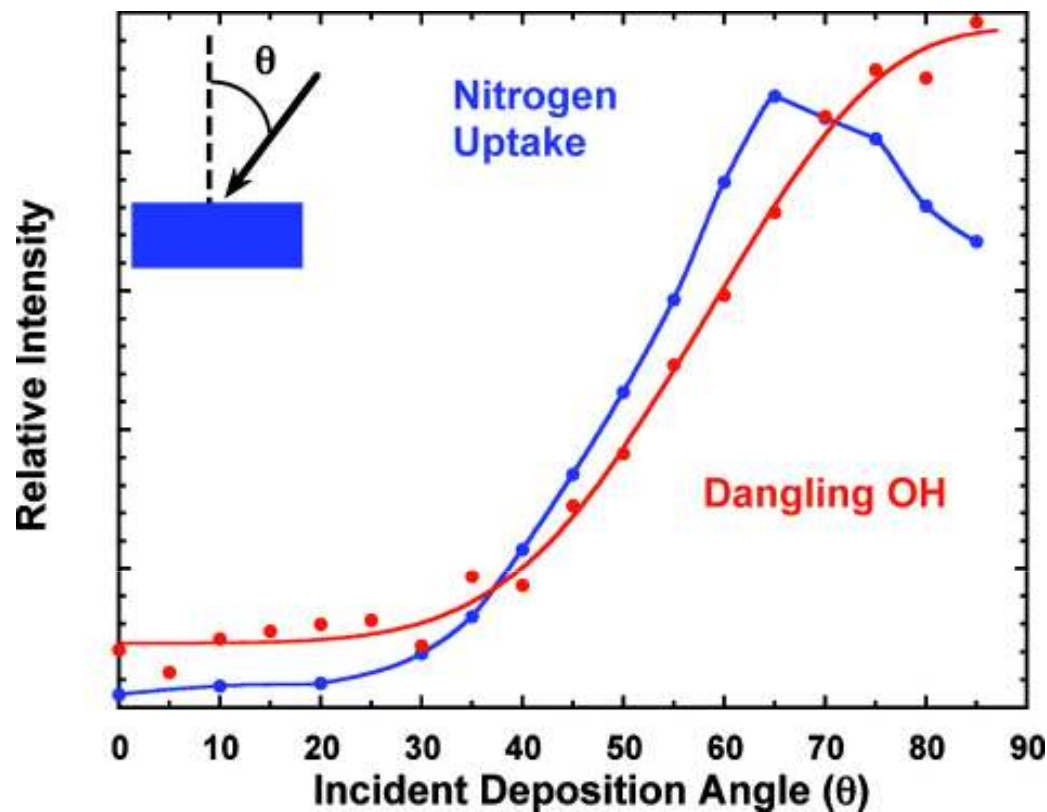


(a) TPD spectra from a composite film with 33 ML of H₂¹⁶O (○) on top of 33 ML of H₂¹⁸O (□). The lines are simulations using a one-dimensional diffusive transport model. (b) TPD spectra from a composite film of 33 ML of H₂O on top of 33 ML of D₂O.

D. Morphology of ASW.

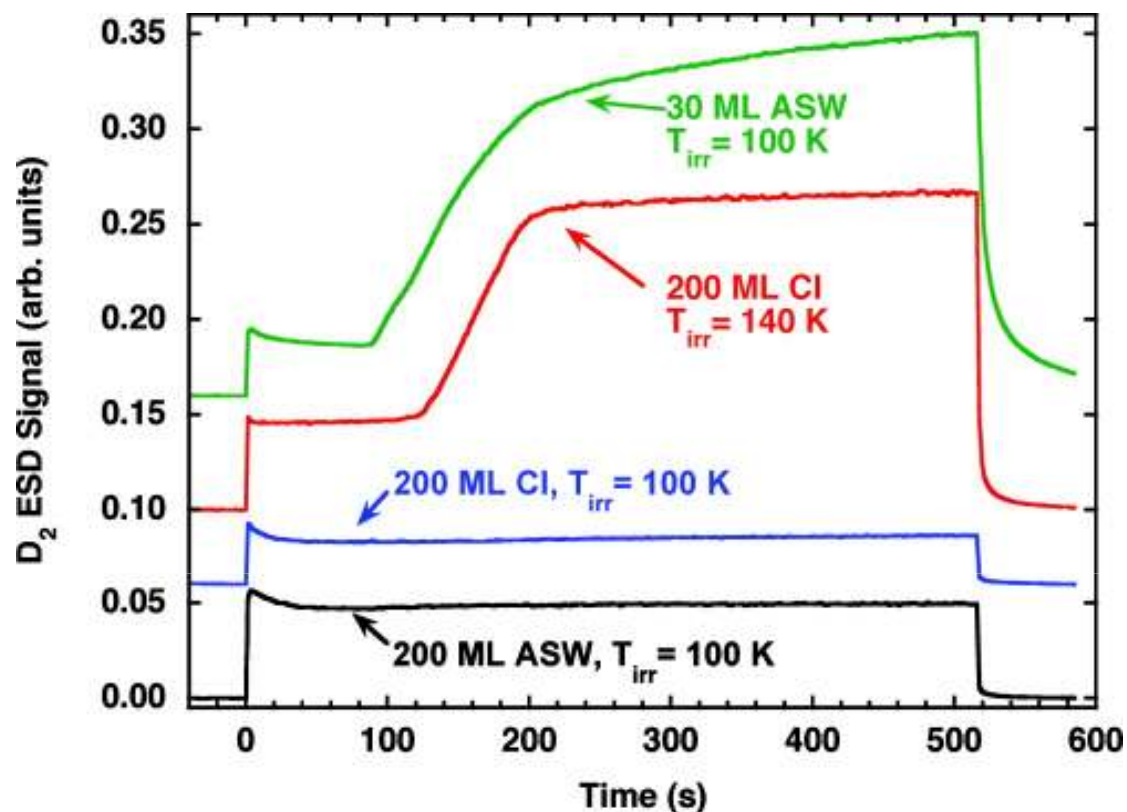


Ballistic deposition model simulations for the growth of ASW films at incident growth angles of 0° (left) and 70° (right).

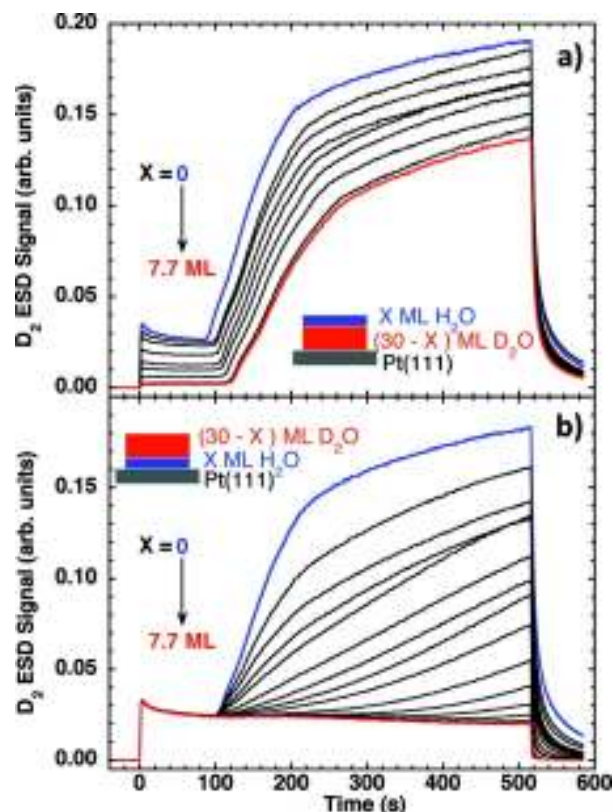


Nitrogen uptake (blue) and dangling OH bond intensity (red) for 100 ML ASW films deposited at various deposition angles.

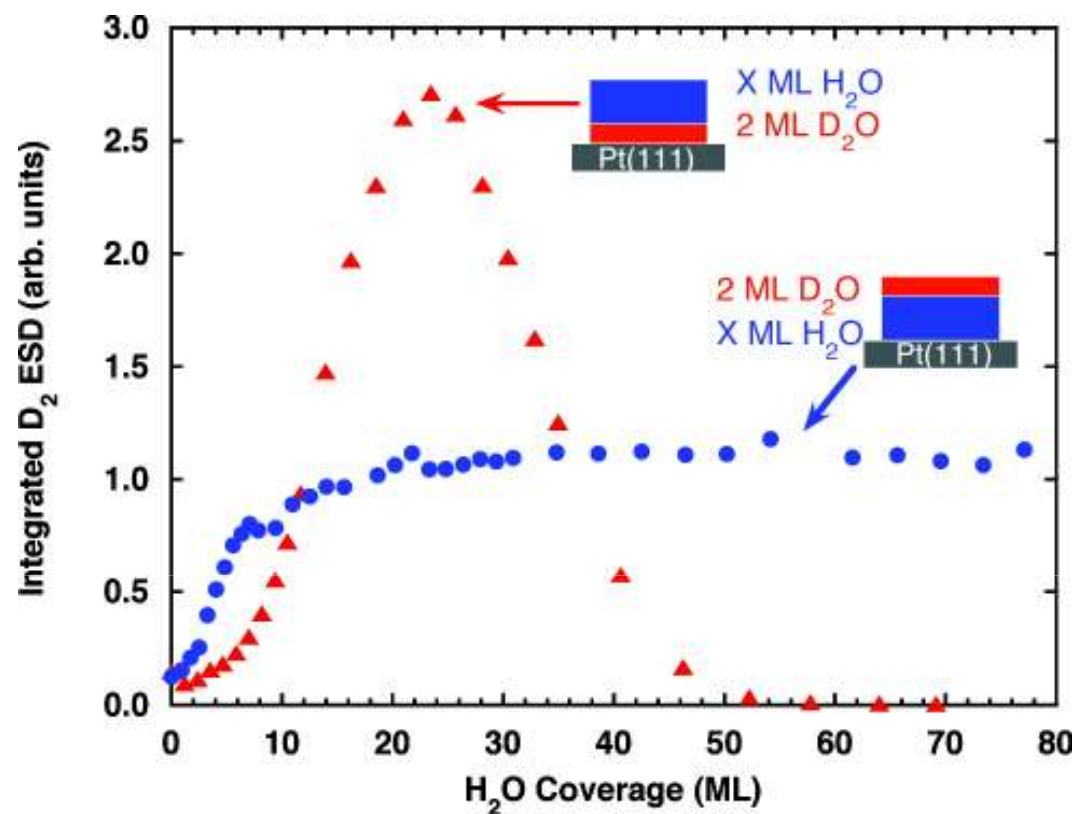
Nonthermal Reactions in ASW Films.



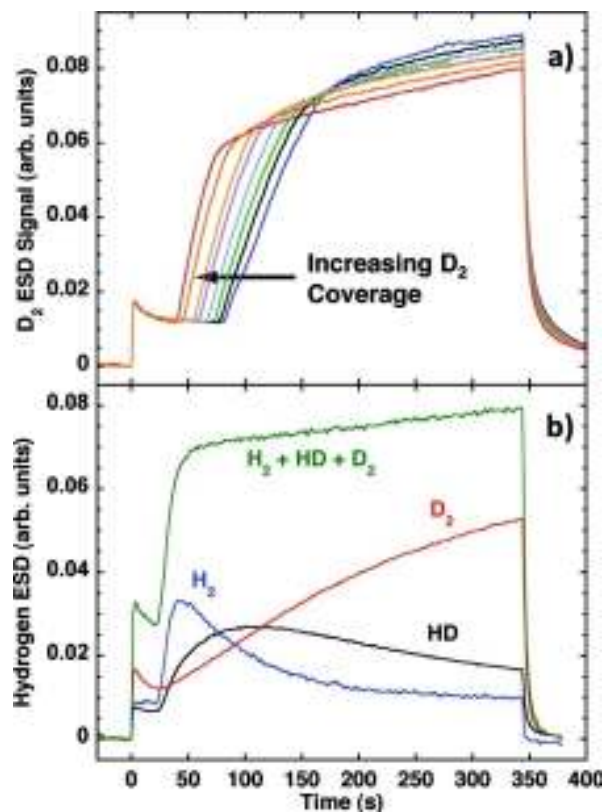
D₂ electron-stimulated desorption (ESD) signals at 100 or 140 K vs time from Cl and ASW D₂O films adsorbed on Pt(111). Incident electron energy is 87 eV. The electron beam is turned on at $t = 0$ s and turned off at $t = 520$ s.



D_2 ESD signals vs time from isotopically layered ASW films of D_2O and H_2O . The films were deposited at 120 K and irradiated at 100 K with 87 eV electrons: (a) $(30 - X)$ ML D_2O capped with X ML of H_2O , Incident electron energy is 87 eV. (b) $(30 - X)$ ML D_2O deposited on top of an X ML H_2O spacer.



Integrated D_2 ESD yields vs H_2O coverage from isotopically layered ASW films of 2 ML D_2O and various coverages of H_2O . Incident electron energy is 87 eV.



D₂, HD, and H₂ ESD yields versus time for 30 ML D₂O films adsorbed on Pt(111) predosed with (a) deuterium atoms or (b) hydrogen atoms.

Conclusion:

- ❖ Thermal and nonthermal properties of water and amorphous materials can be studied by using ASW as a model.
- ❖ Future work will use ASW films as a model “solvent” to explore the physical and reaction properties of aqueous supercooled liquid solutions.
- ❖ The experiments suggest that mobile electronic excitations are responsible for the reactions at the interfaces of thin ASW films. Protonic defects (e.g., H_3O^+), delocalized electrons, holes, and excitons are potential candidates for the mobile excitations.

THANKS